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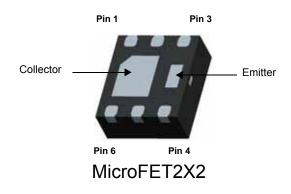
# FJMA790 PNP Epitaxial Silicon Transistor

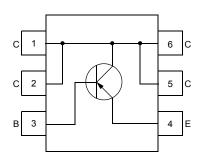
#### May 2014

## High current surface mount PNP silicon switching transistor for load management in portable applications

- · High Collector current
- Low Collector-Emitter Saturation Voltage
- · RoHS Compliant







#### Absolute Maximum Ratings Ta = 25°C unless otherwise noted

Symbol	Parameter		Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage		-35	V
V <sub>EBO</sub>	Emitter-Base Voltage		-5	V
I <sub>C</sub>	Collector Current (DC)		-2	А
P <sub>D</sub>	· · · · · · · · · · · · · · · · · · ·	Note1) lote2)	1.56 0.8	W W
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		-55 ~ 150	°C

#### Thermal Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter		Max.	Units
$R\Theta_JA$	Thermal Resistance, Junction to Ambient	Note1)	80	°C/W
		Note2)	154	°C/W

Note1): The device mounted on a  $1 \text{inch}^2$  pad of 2 oz copper pad on a  $1.5 \times 1.5$  in. board of FR-4 material.

Note2): The device mounted on a minimum pad of 2 oz copper pad on a 1.5 × 1.5 in. board of FR-4 material

## **Electrical Characteristics** $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-50			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> = 0	-35			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_C = -100 \mu A, I_C = 0$	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -35V, I_{C} = 0$			-0.1	μА
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -4V, I_{C} = 0$			-0.1	μА
h <sub>FE</sub>	DC Current Gain	$V_{CE}$ = -1.5V, $I_{C}$ = -1.5A $V_{CE}$ = -1.5V, $I_{C}$ = -1.5A $V_{CE}$ = -3V, $I_{C}$ = -2A $V_{CE}$ = -2V, $I_{C}$ = -500mA	100 100 100 100		400	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_C$ = -500mA, $I_B$ = -5mA $I_C$ = -1A, $I_B$ = -10mA $I_C$ = -2A, $I_B$ = -50mA			-250 -350 -450	mV mV mV
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -1A, I <sub>B</sub> = -10mA			-0.9	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	V <sub>CE</sub> = -2V, I <sub>C</sub> = -1A			-0.9	V

## **Package Marking and Ordering Information**

<b>Device Marking</b>	Device	Package	Reel Size	Tape Width	Quantity
790	FJMA790	MLP 2×2 Single	7"	8mm	3,000 units

#### **Typical Characteristics**

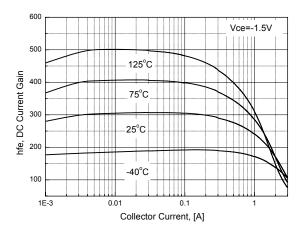


Figure 1. DC Current Gain, Vce=1.5V

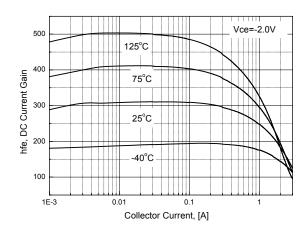


Figure 2. DC Current Gain, Vce=2V

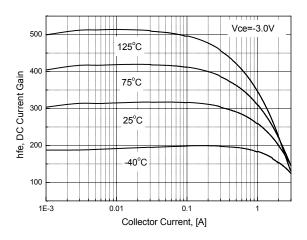


Figure 3. DC Current Gain, Vce=3V

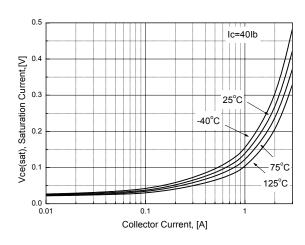


Figure 4. Collector-Emitter Satuation Voltage(1)

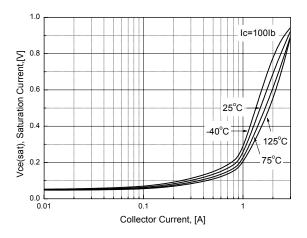


Figure 5. Collector-Emitter Satuation Voltage(2)

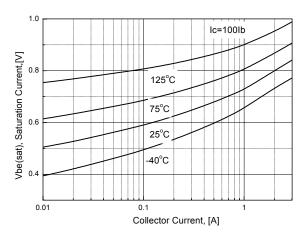


Figure 6. Base-Emitter Saturation Voltage

## Typical Performance Characteristics (Continued)

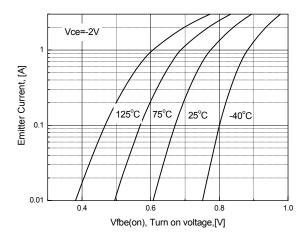
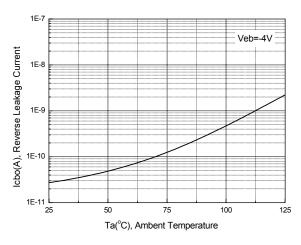


Figure 7. Base- Emitter Turn On Voltage

Figure 8. Collector-Base Leakage Current



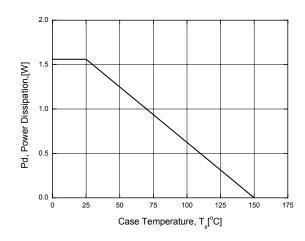
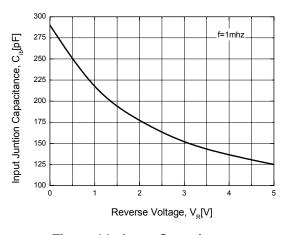


Figure 9. Base-Emitter Leakage Current

Figure 10. Power Derating



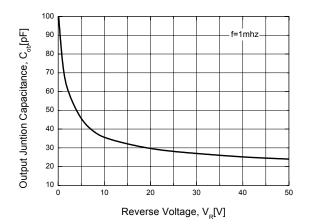
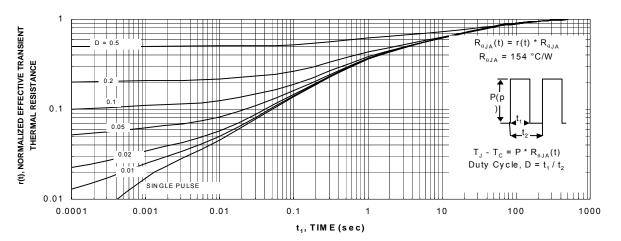


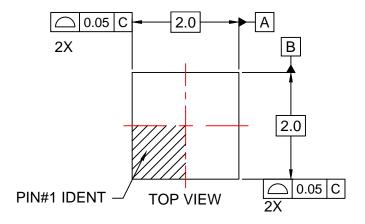
Figure 11. Input Capacitance

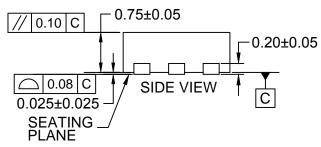
Figure 12. Output Capacitance

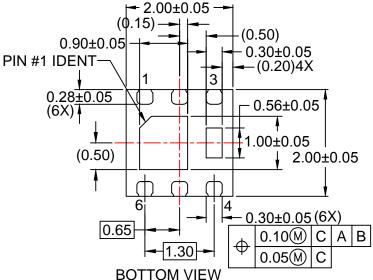
## Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response



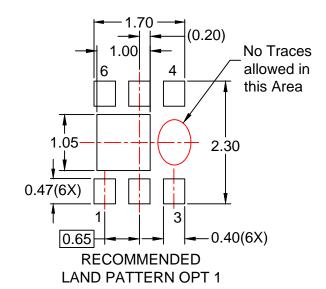


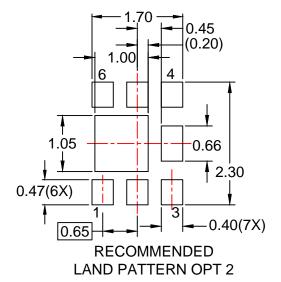




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